

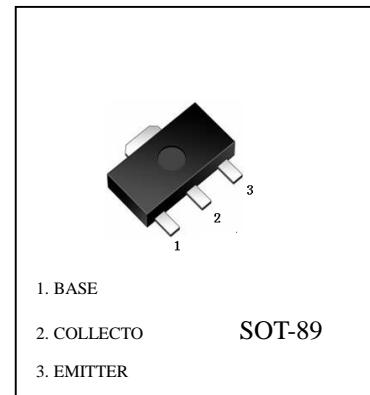
FEATURES

- Small flat package.
- Low saturation voltage $V_{CE(sat)}=-0.5V$
- High speed switching time
- $PC=1.0$ to $2.0W$

z High saturation current capability

Maximum Ratings ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current -Continuous	I_C	2	A
Peak Base Current	I_{BM}	0.4	A
Collector Power dissipation	P_C	1	W
Storage Temperature	T_{stg}	-55 to +150	$^{\circ}C$

2SC1766 (NPN)


ELECTRICAL CHARACTERISTICS (@ $T_a=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector cut-off current	I_{CBO}	$V_{CB}=50V, I_E=0$			0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=5V, I_C=0$			0.1	μA
DC current gain	h_{FE}	$V_{CE}=2V, I_C=500mA$	70		240	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=1A, I_B=50mA$			0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=1A, I_B=50mA$			1.2	mV
Transition frequency	f_T	$V_{CE}=2V, I_c=0.5A$ $f=100MHz$		120		MHz
Collector output capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$		40		pF

 CLASSIFICATION OF h_{FE}

Rank	P	Q	Y
Range	82-180	120-270	180-390
Marking	P1766	Q1766	Y1766

2SC1766 Typical Characteristics

Figure 1. V_{CE} - I_C

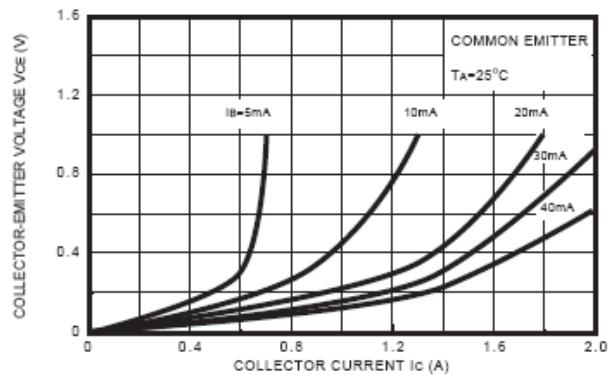


Figure 2. V_{CE} - I_C

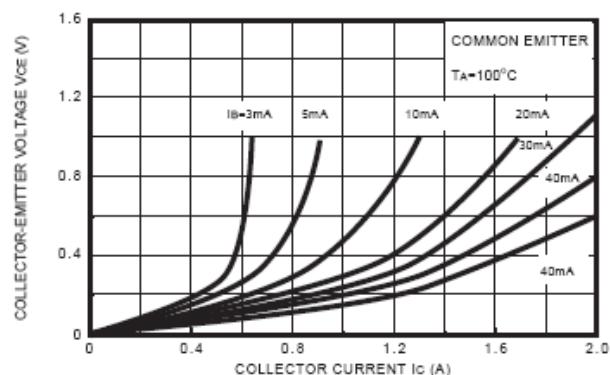


Figure 3. V_{CE} - I_C

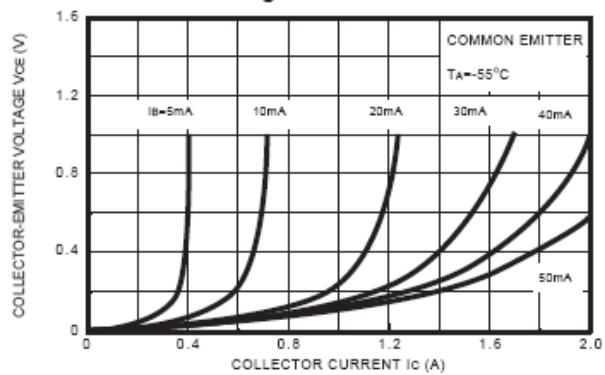


Figure 4. h_{FE} - I_C

